



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## ECH8315 — P-Channel Silicon MOSFET — General-Purpose Switching Device Applications

### Features

- Low ON-resistance
- 4V drive
- Halogen free compliance
- Protection diode in

### Specifications

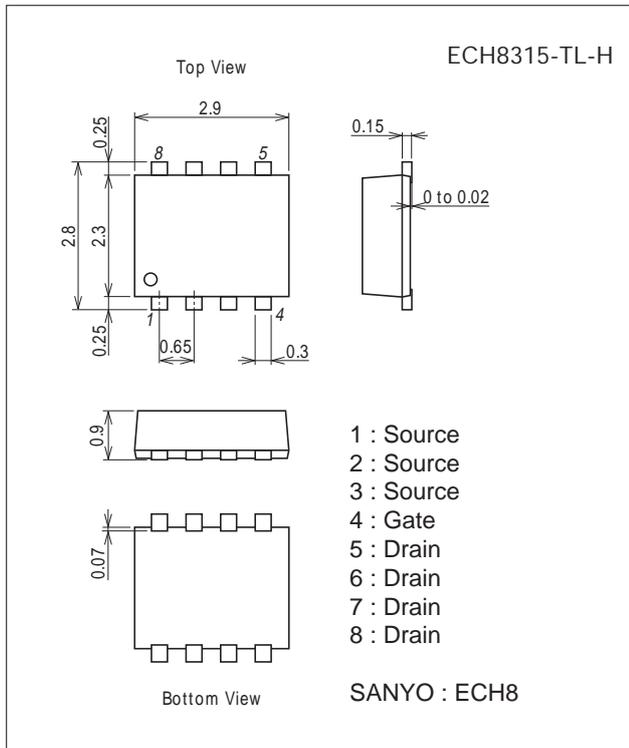
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		-30	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±20	V
Drain Current (DC)	I <sub>D</sub>		-7.5	A
Drain Current (Pulse)	I <sub>DP</sub>	PW≤10μs, duty cycle≤1%	-40	A
Allowable Power Dissipation	P <sub>D</sub>	When mounted on ceramic substrate (900mm <sup>2</sup> ×0.8mm)	1.5	W
Channel Temperature	T <sub>ch</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

### Package Dimensions

unit : mm (typ.)

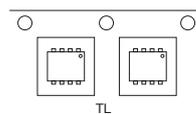
7011A-002



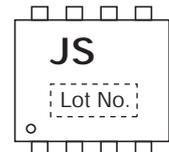
### Product & Package Information

- Package : ECH8
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

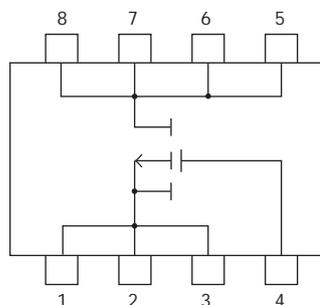
Packing Type : TL



Marking



### Electrical Connection

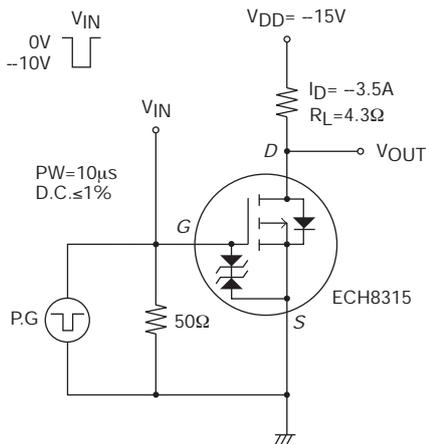


# ECH8315

## Electrical Characteristics at Ta=25°C

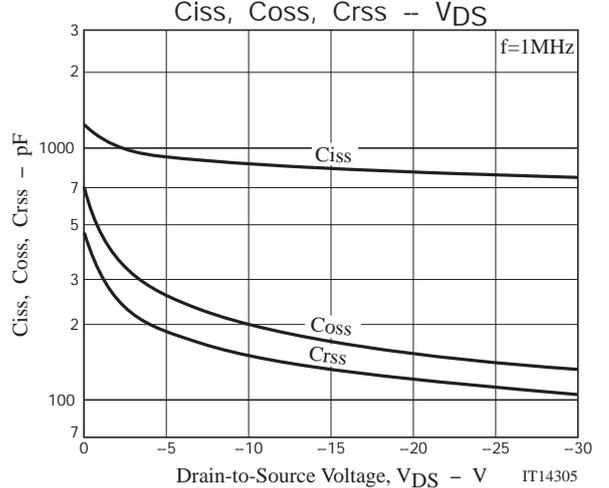
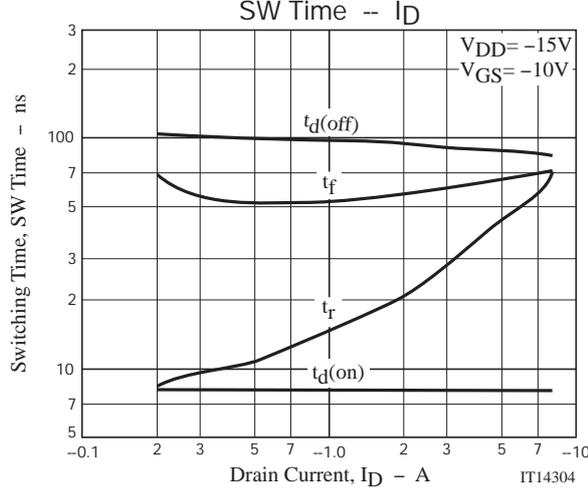
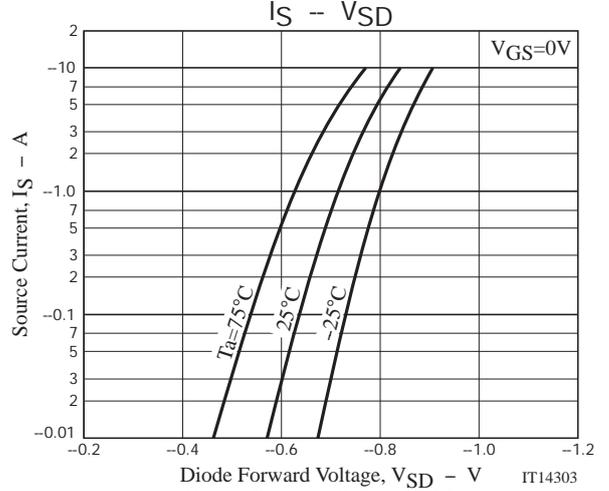
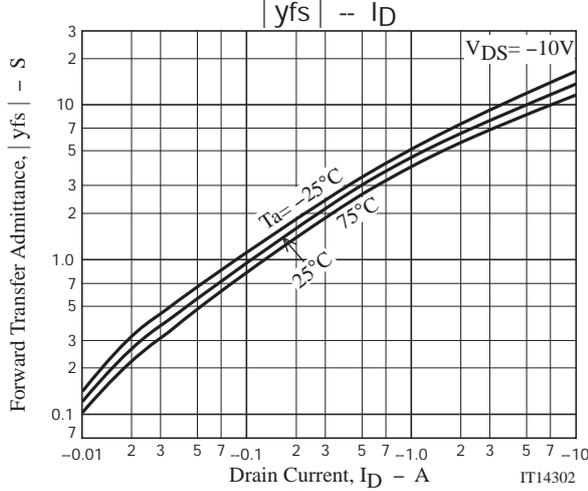
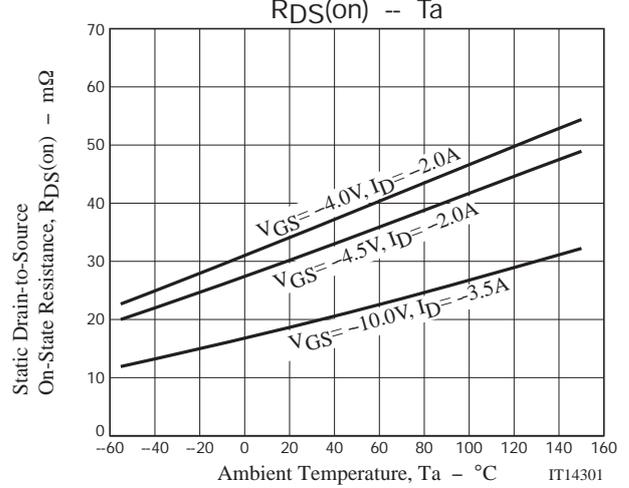
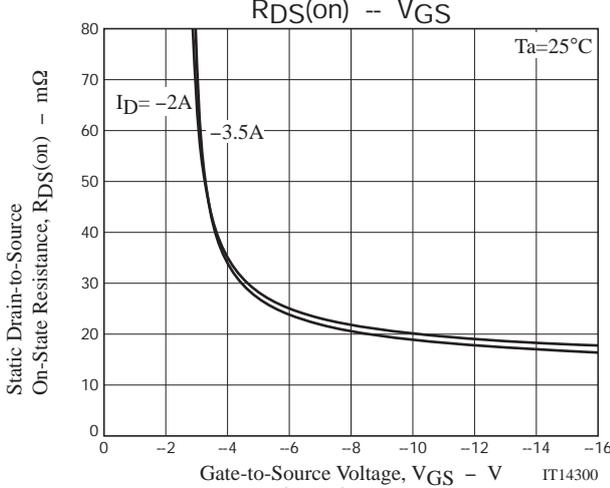
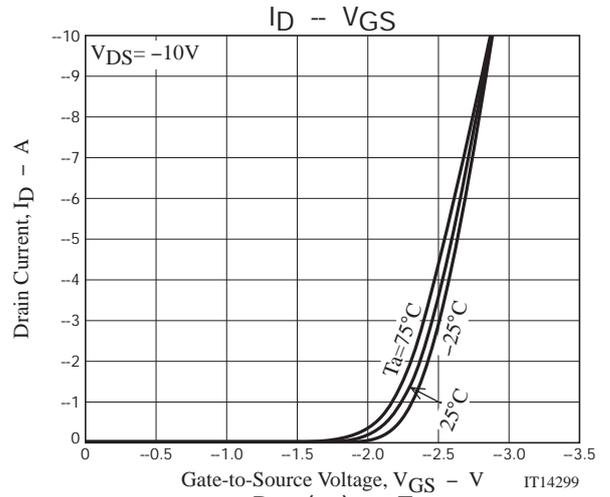
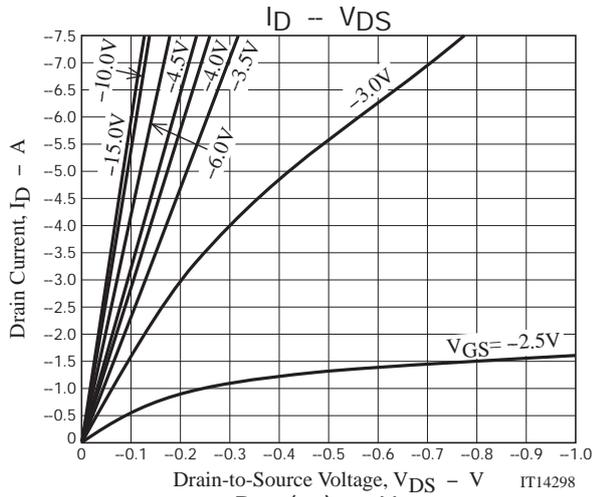
Parameter	Symbol	Conditions	Ratings			Unit
			min.	typ.	max.	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =-1mA, V <sub>GS</sub> =0V	-30			V
Zero-Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V			-1	μA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0V			±10	μA
Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> =-10V, I <sub>D</sub> =-3.5A	5	8.4		S
Static Drain-to-Source On-State Resistance	R <sub>DS(on)1</sub>	I <sub>D</sub> =-3.5A, V <sub>GS</sub> =-10V		19	25	mΩ
	R <sub>DS(on)2</sub>	I <sub>D</sub> =-2A, V <sub>GS</sub> =-4.5V		31	44	mΩ
	R <sub>DS(on)3</sub>	I <sub>D</sub> =-2A, V <sub>GS</sub> =-4V		35	49	mΩ
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-10V, f=1MHz		875		pF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =-10V, f=1MHz		200		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	V <sub>DS</sub> =-10V, f=1MHz		150		pF
Turn-ON Delay Time	t <sub>d(on)</sub>	See specified Test Circuit.		8.1		ns
Rise Time	t <sub>r</sub>			33		ns
Turn-OFF Delay Time	t <sub>d(off)</sub>			92		ns
Fall Time	t <sub>f</sub>			60		ns
Total Gate Charge	Q <sub>g</sub>				18	
Gate-to-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-15V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-7.5A		2.1		nC
Gate-to-Drain "Miller" Charge	Q <sub>gd</sub>			4.7		nC
Diode Forward Voltage	V <sub>SD</sub>		I <sub>S</sub> =-7.5A, V <sub>GS</sub> =0V		-0.82	-1.2

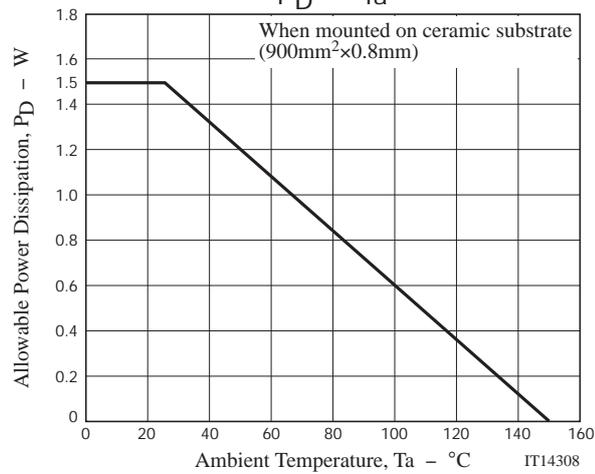
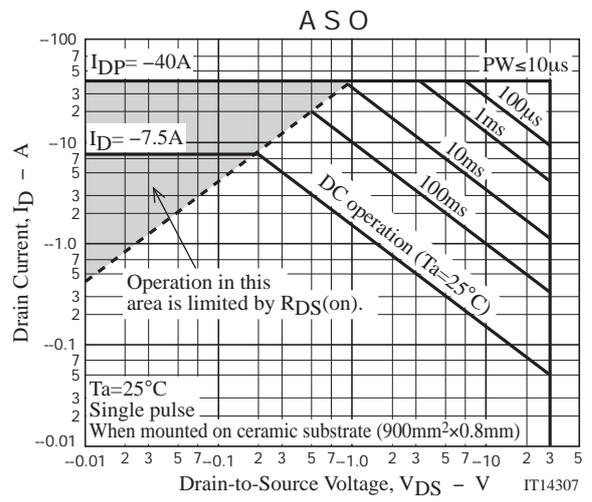
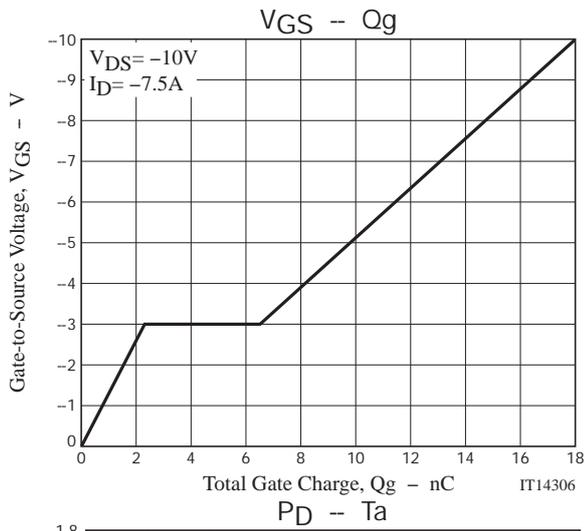
## Switching Time Test Circuit



## Ordering Information

Device	Package	Shipping	memo
ECH8315-TL-H	ECH8	3,000pcs./reel	Pb-Free and Halogen Free





Embossed Taping Specification

ECH8315-TL-H

1. Packing Format

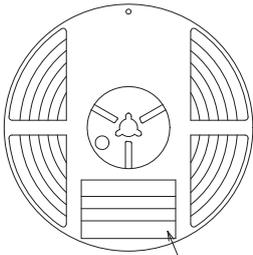
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
ECH8	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label  
(unit :mm)

Outer box label

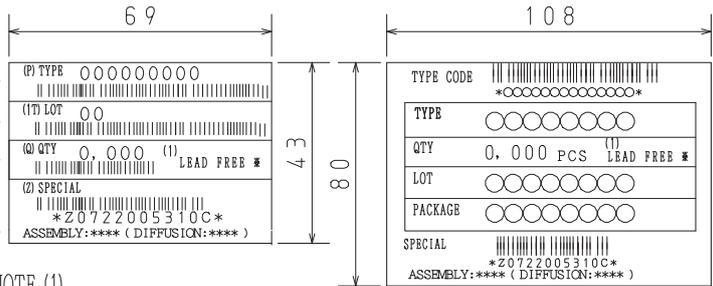
It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

Packing method



Reel label

Type No.  
LOT No.  
Quantity  
Origin



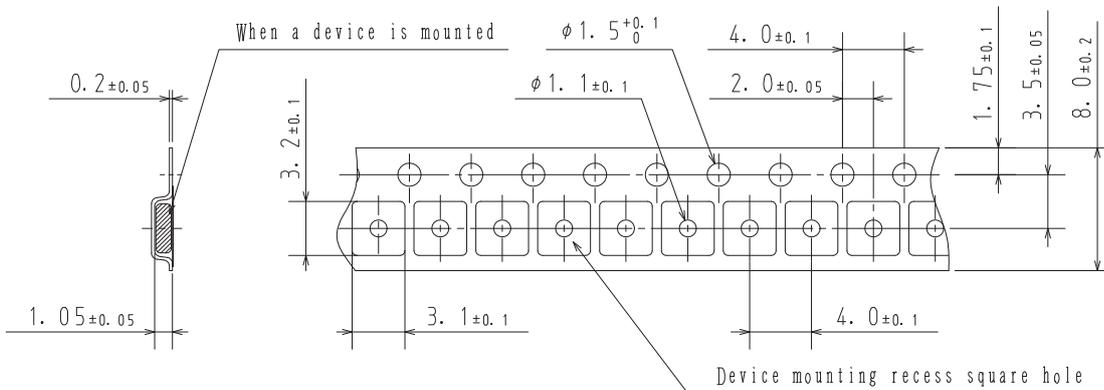
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

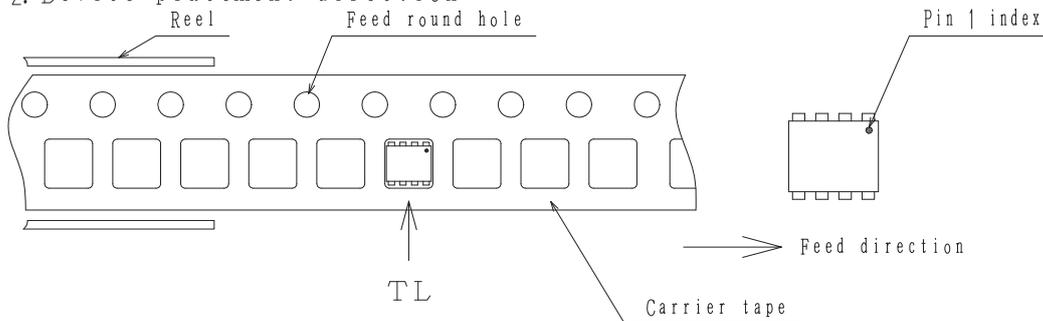
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



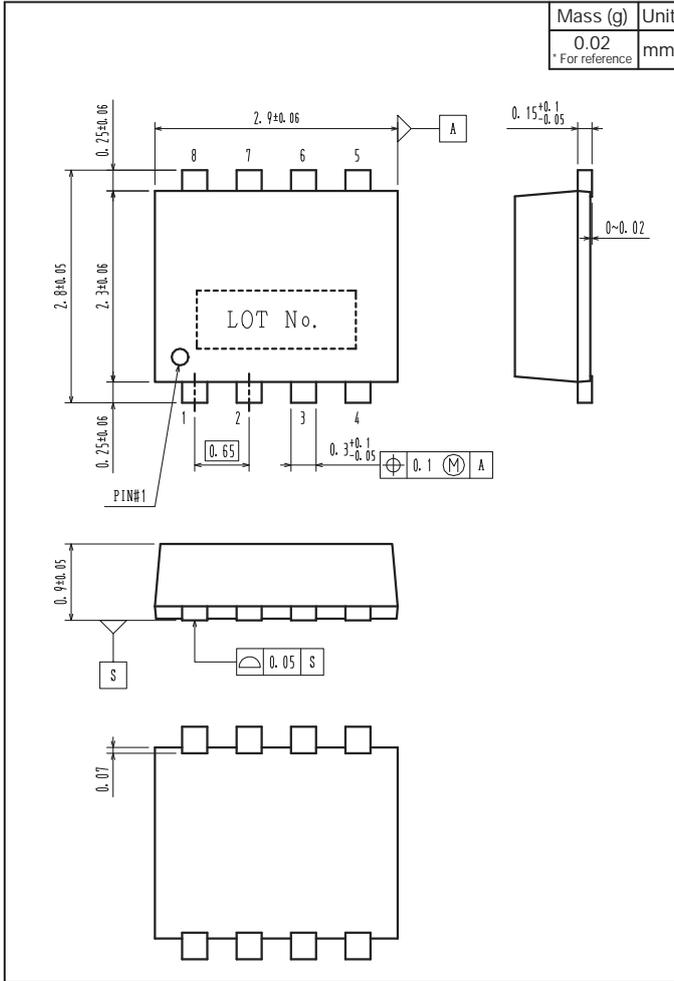
2-2. Device placement direction



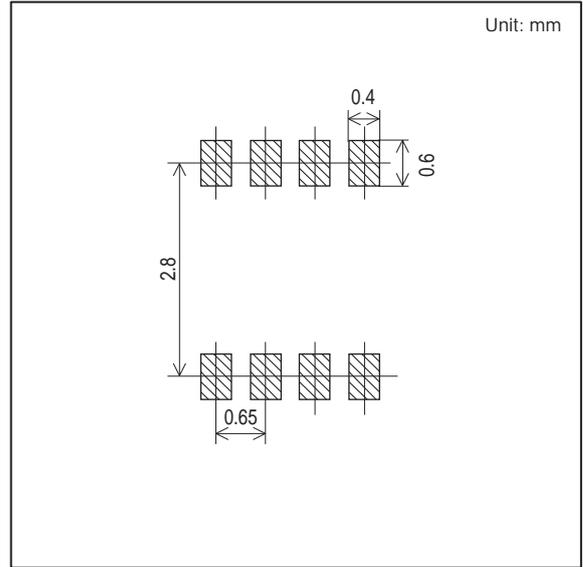
Those with pin 1 index on the feed hole side.....TL

# ECH8315

## Outline Drawing ECH8315-TL-H



## Land Pattern Example



Note on usage : Since the ECH8315 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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